



PTO/SB/30 (10-01)

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<b>REQUEST FOR CONTINUED EXAMINATION (RCE) TRANSMITTAL</b> Address to: Commissioner for Patents Box RCE Washington, DC 20231	
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<i>Application Number</i>	09/772,986-Conf. #2637
<i>Filing Date</i>	January 31, 2001
<i>First Named Inventor</i>	Hisao Hayashi et al.
<i>Group Art Unit</i>	2811
<i>Examiner Name</i>	T. F. Tran
<i>Attorney Docket No.</i>	SON-2010

**This is a Request for Continued Examination (RCE) under 37 CFR 1.114 of the above-identified application.**

Request for Continued Examination (RCE) practice under 37 CFR 1.114 does not apply to any utility or plant application filed prior to June 8, 1995, or to any design application. See Instruction Sheet for RCEs (not to be submitted to the USPTO) on page 2.

**1. Submission required under 37 CFR 1.114**

a.  Previously submitted

- i.  Consider the amendment(s)/reply under 37 CFR 1.116 previously filed on \_\_\_\_\_ (Any unentered amendment(s) referred to above will be entered).
- ii.  Consider the arguments in the Appeal Brief or Reply Brief previously filed on \_\_\_\_\_
- iii.  Other \_\_\_\_\_

b.  Enclosed

- i.  Amendment/Reply (Preliminary Amendment)
- ii.  Affidavit(s)/Declaration(s)
- iii.  Information Disclosure Statement (IDS)
- iv.  Other \_\_\_\_\_

**2. Miscellaneous**

a.  Suspension of action on the above-identified application is requested under 37 CFR 1.103(c) for a period of \_\_\_\_\_ months. (Period of suspension shall not exceed 3 months; Fee under 37 CFR 1.17(i) required)

b.  Other \_\_\_\_\_

**3. Fees** The RCE fee under 37 CFR 1.17 (e) is required by 37 CFR 1.114 when the RCE is filed.

a.  The Director is hereby authorized to charge the following fees, or credit any overpayments, to Deposit Account No. 18-0013

- i.  RCE fee required under 37 CFR 1.17(e)
- ii.  Extension of time fee (37 CFR 1.136 and 1.17)
- iii.  Other \_\_\_\_\_

b.  Check in the amount of \$ \_\_\_\_\_ Enclosed

c.  Payment by credit card (Form PTO-2038 enclosed)

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**SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT REQUIRED**

Name (Print/Type)	Ronald P. Kahanen	Registration No. (Attorney/Agent)	24,104
Signature			Date
		January 2, 2003	

01/03/2003 JADDD01 00000101 180013 09772986

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SON-2010

Ser. No. 09/772,986

RCE 2800

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
Hisao HAYASHI et al. ) Group Art Unit: 2811  
Appln. No.: 09/772,986 ) Examiner: Tran, Thien F.  
Filed: January 31, 2001 )  
For: THIN FILM SEMICONDUCTOR )  
DEVICE, DISPLAY DEVICE )  
USING SUCH THIN FILM )  
SEMICONDUCTOR DEVICE AND )  
MANUFACTURING METHOD )  
THEREOF )

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BOX RCE  
Commissioner of Patents  
Washington, D.C. 20231

PRELIMINARY AMENDMENT

Sir:

Responsive to the final Office Action dated November 12, 2002, (Paper No. 11), please amend the above-referenced application as follows.

IN THE CLAIMS:

Please rewrite claims 1 and 5 as set forth below in clean form. Additionally, in accordance with 37 CFR 1.121(c)(1)(ii), amended claims 1 and 5 are set forth in a marked-up version in the pages attached to this Amendment.

1. (Amended) A thin film semiconductor device comprising:  
an insulating substrate; and  
a thin film transistor formed on said insulating substrate, wherein  
said thin film transistor is formed in a bottom gate structure having gate  
electrode, a gate insulating film, and a semiconductor thin film stacked in the order  
from below upward, and